Vishay Semiconductors



Hyperfast Rectifier, 30 A FRED Pt[®]

3 TO-247AD 2L Base cathode 02 3

Anode

PRIMARY CHARACTERISTICS								
I _{F(AV)}	30 A							
V _R	600 V							
V _F at I _F	1.4 V							
t _{rr} typ.	26 ns							
T _J max.	175 °C							
Package	TO-247AD 2L							
Circuit configuration	Single							

Cathode

FEATURES

- Low forward voltage drop
- · Hyperfast soft recovery time
- 175 °C operating junction temperature
- · Designed and qualified according to commercial HALOGEN FREE qualification



COMPLIANT

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS					
Repetitive peak reverse voltage	V _{RRM}		600	V					
Average rectified forward current	I _{F(AV)}	T _C = 112 °C	30	٨					
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave	240	A					
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Conservation and the second	V _F	I _F = 30 A	-	2.0	2.65	65 V			
Forward voltage		I _F = 30 A, T _J = 150 °C	-	1.4	1.8				
Povoroo lookago ourront	I _R	V _R = V _R rated	-	0.02	30				
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μA			
Junction capacitance	CT	V _R = 600 V	-	20	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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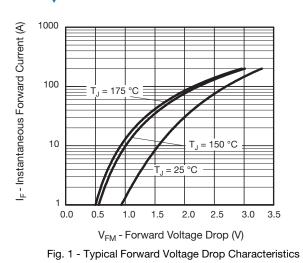
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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns			
		T _J = 125 °C		-	70	-				
Pook receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/µs V _B = 200 V	-	3.5	-	А			
Peak recovery current		T _J = 125 °C		-	7.6	-	A			
Reverse recovery charge	0	T _J = 25 °C	• n = 200 •	-	50	-	nC			
	Q _{rr}	T _J = 125 °C]	-	280	-				

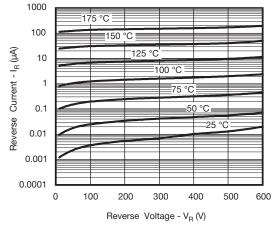
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Thermal resistance, junction to case	R _{thJC}		-	0.7	1.1	°C/W			
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	5.5	-	g			
Weight			-	0.2	-	oz.			
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)			
Marking device		Case style TO-247AD 2L		EPH	3006L				

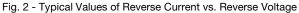
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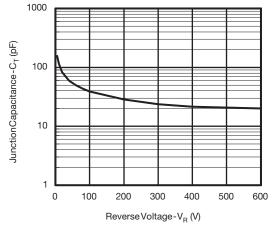
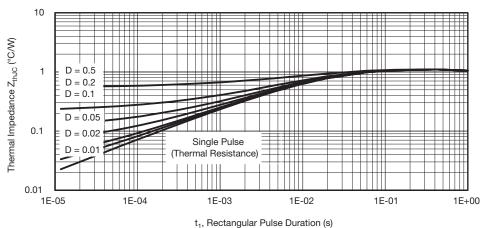
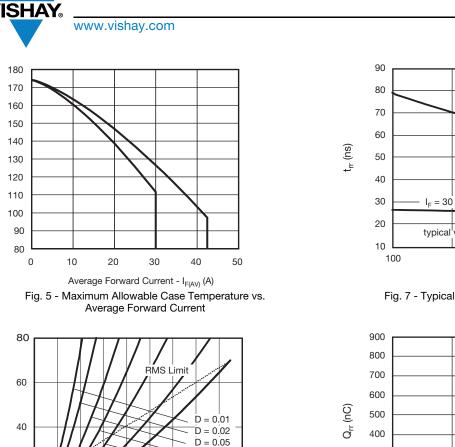


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



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Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics



D = 0.1

D = 0.2

D = 0.5

DC

Average Forward Current - I_{F(AV)} (A)

Fig. 6 - Forward Power Loss Characteristics

Allowable Case Temperature (°C)

Average Power Loss (W)

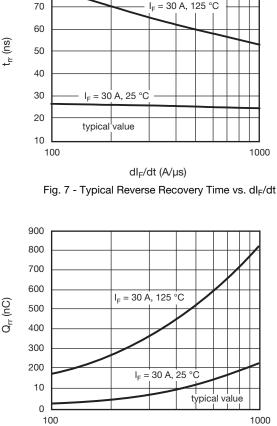
20

0

0

5 10 15 20 25 30 35 40 45

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dI_F/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl_F/dt

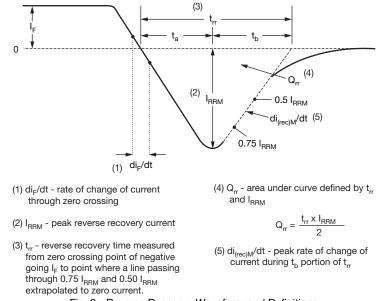


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	Е	Р	н	30	06	L	-N3
		2	3	4	5	6	7	8
	1 -	Visł	nay Sem	niconduc	tors pro	oduct		
	2 -		= single					
		• E	= single	diode				
	3 -	P =	TO-247	,				
	4 -	H =	hyperfa	st recov	ery time	e		
	5 -	Cur	rent cod	le (30 =	30 A)			
	6 -	Volt	age cod	le (06 =	600 V)			
	7 -	L =	long lea	d				
	8 -			ntal digit en-free,		complia	nt, and	totally I

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-EPH3006L-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536					
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648					
SPICE model		www.vishay.com/doc?96580					



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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51 BSC 0.217 BSC				
D2	0.51	1.35	0.020	0.053				•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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